

HMC12N120T

Silicon Carbide Schottky Diode

| | | | |
|--|---|------|------|
| V_{RRM} | = | 1200 | V |
| I_F ($T_C \leq 135^\circ\text{C}$) | = | 19 | A** |
| Q_C | = | 39 | nC** |

Features

- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Positive Temperature Coefficient on V_F
- Temperature-independent Switching
- 175°C Operating Junction Temperature

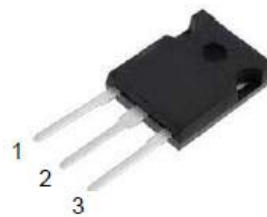
Benefits

- Replace Bipolar with Unipolar Device
- Reduction of Heat Sink Size
- Parallel Devices Without Thermal Runaway
- Essentially No Switching Losses

Applications

- Switch Mode Power Supplies
- Power Factor Correction
- Motor drive, PV Inverter, Wind Power Station

Package



TO-247-3



| Part Number | Package | Marking |
|-------------|----------|------------|
| HMC12N120T | TO-247-3 | HMC12N120T |

Maximum Ratings

| Symbol | Parameter | Value | Unit | Test Conditions | Note |
|----------------|--|-------------------------|------------------|---|-------|
| V_{RRM} | Repetitive Peak Reverse Voltage | 1200 | V | $T_C = 25^\circ\text{C}$ | |
| V_{RSM} | Surge Peak Reverse Voltage | 1200 | V | $T_C = 25^\circ\text{C}$ | |
| V_R | DC Blocking Voltage | 1200 | V | $T_C = 25^\circ\text{C}$ | |
| I_F | Forward Current (Per leg/Device) | 19/38 9.5/19 6/12 | A | $T_C \leq 25^\circ\text{C}$ $T_C \leq 135^\circ\text{C}$ $T_C \leq 160^\circ\text{C}$ | |
| I_{FSM} | Non-Repetitive Forward Surge Current | 60* | A | $T_C = 25^\circ\text{C}$, $t_p = 8.3\text{ms}$, Half Sine Wave | |
| P_{tot} | Power Dissipation (Per leg/Device) | 136/ 272 | W | $T_C = 25^\circ\text{C}$ | Fig.3 |
| T_C | Maximum Case Temperature | 160 | $^\circ\text{C}$ | | |
| T_J, T_{STG} | Operating Junction and Storage Temperature | -55 to 175 | $^\circ\text{C}$ | | |
| | TO-247 Mounting Torque | 1 | Nm | M3 Screw | |

*Per Leg, **Per Device

Electrical Characteristics (Per Leg)

| Symbol | Parameter | Typ. | Max. | Unit | Test Conditions | Note |
|--------|-------------------------|-----------------|------------|---------|--|-------|
| V_F | Forward Voltage | 1.55 2.2 | 1.8 2.5 | V | $I_F = 6A, T_J = 25^\circ C$ $I_F = 6A, T_J = 175^\circ C$ | Fig.1 |
| I_R | Reverse Current | 2 10 | 20 200 | μA | $V_R = 1200V, T_J = 25^\circ C$ $V_R = 1200V, T_J = 175^\circ C$ | Fig.2 |
| C | Total Capacitance | 387 28 22 | / | pF | $V_R = 0V, T_J = 25^\circ C, f = 1MHz$ $V_R = 400V, T_J = 25^\circ C, f = 1MHz$ $V_R = 800V, T_J = 25^\circ C, f = 1MHz$ | Fig.5 |
| Q_C | Total Capacitive Charge | 19.5 | / | nC | $V_R = 800V, I_F = 6A$ $di/dt = 200A/\mu s, T_J = 25^\circ C$ | Fig.4 |

Thermal Characteristics

| Symbol | Parameter | Typ. | Unit | Note |
|-----------------|---|----------------|--------------|-------|
| $R_{\theta JC}$ | Thermal Resistance from Junction to Case | 1.1* 0.55** | $^\circ C/W$ | Fig.6 |
| $R_{\theta JA}$ | Thermal Resistance from Junction to Ambient | 80 | $^\circ C/W$ | |
| T_{sold} | Soldering Temperature | 260 | $^\circ C$ | |

*Per Leg, **Per Device

Typical Performance (Per Leg)

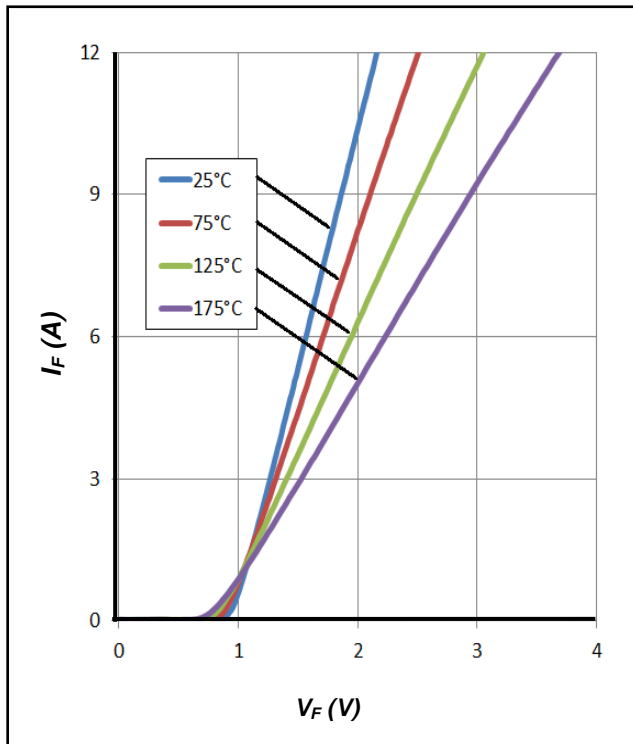


Figure 1. Forward Characteristics

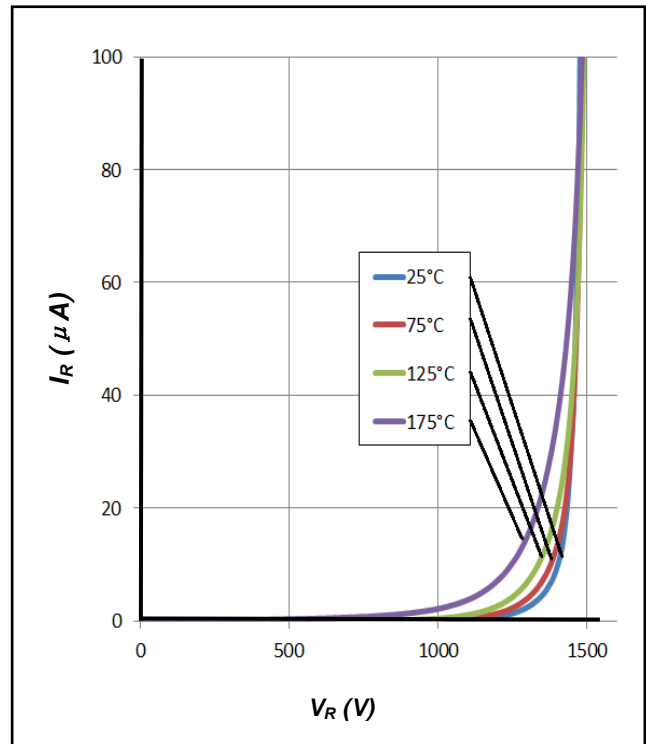


Figure 2. Reverse Characteristics

Typical Performance (Per Leg)

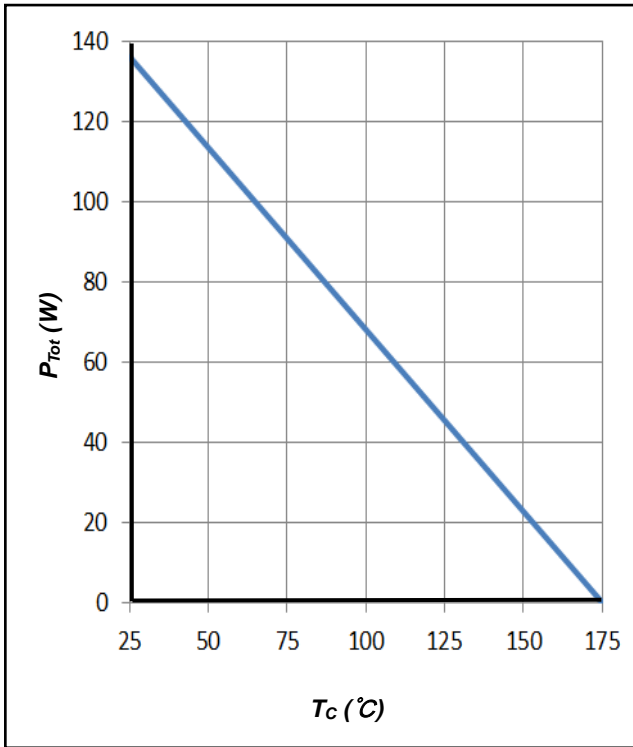


Figure 3. Power Derating

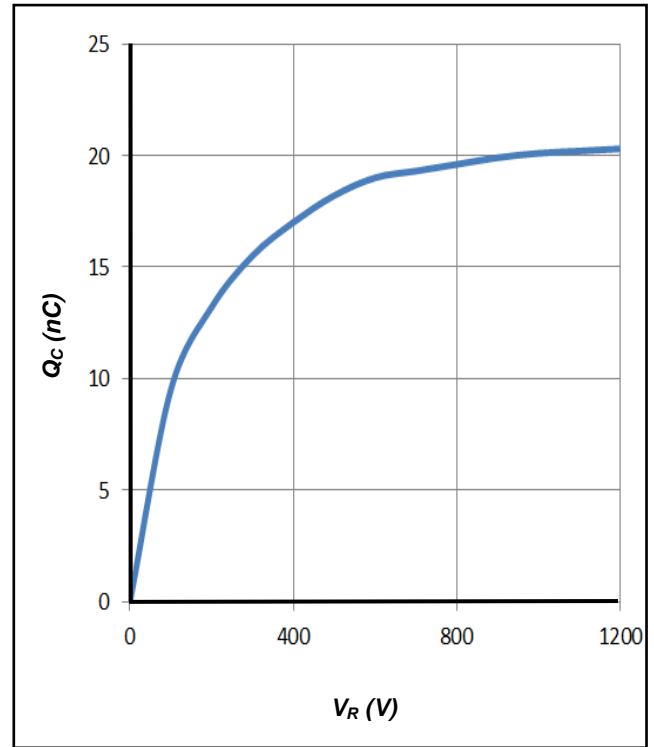


Figure 4. Total Capacitive Charge vs. Reverse Voltage

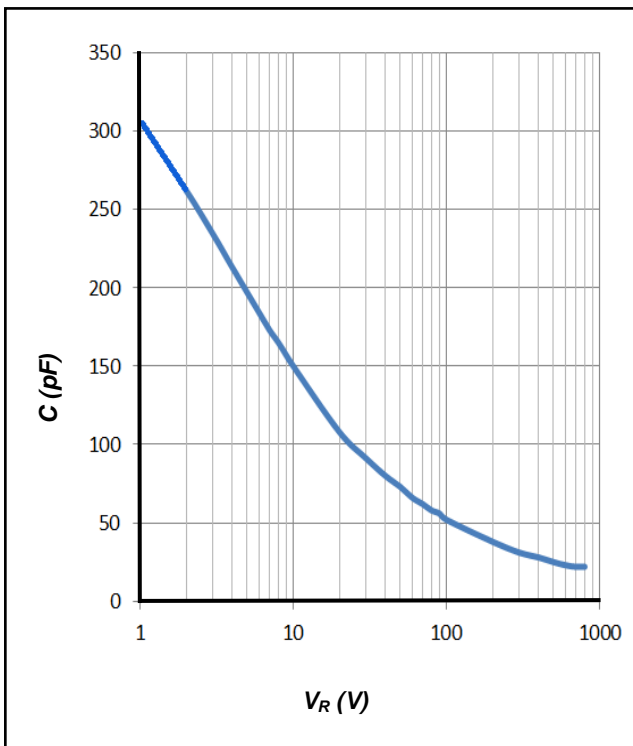


Figure 5. Total Capacitance vs. Reverse Voltage

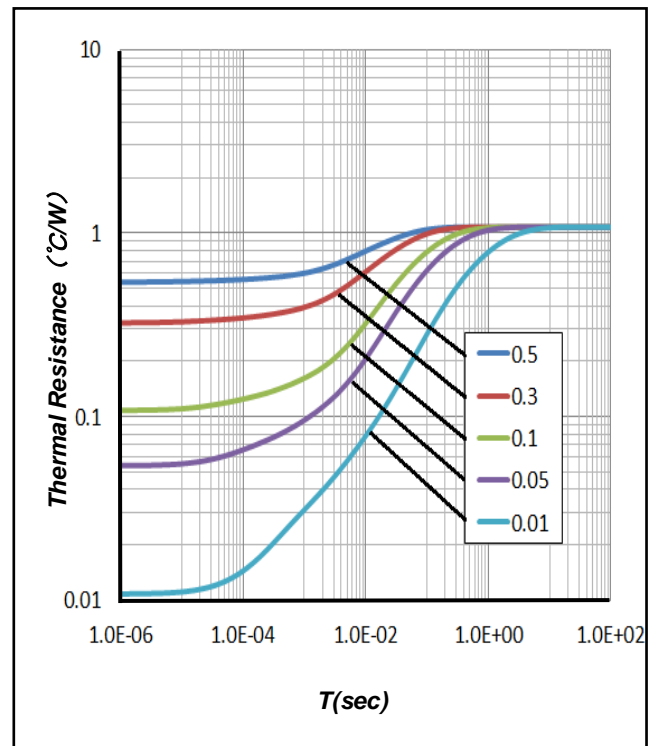
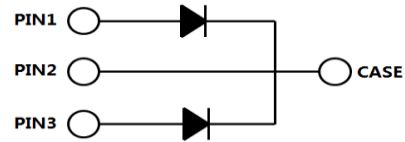
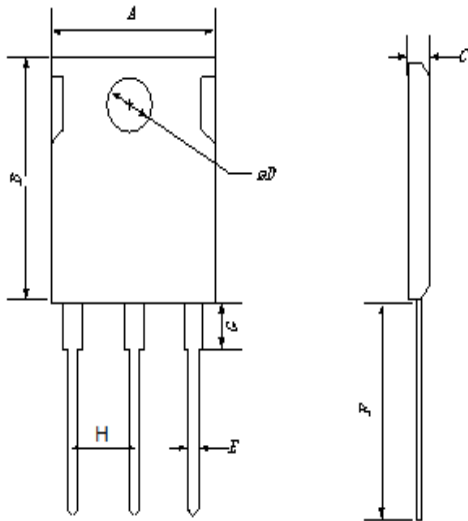


Figure 6. Transient Thermal Impedance

Package Dimensions

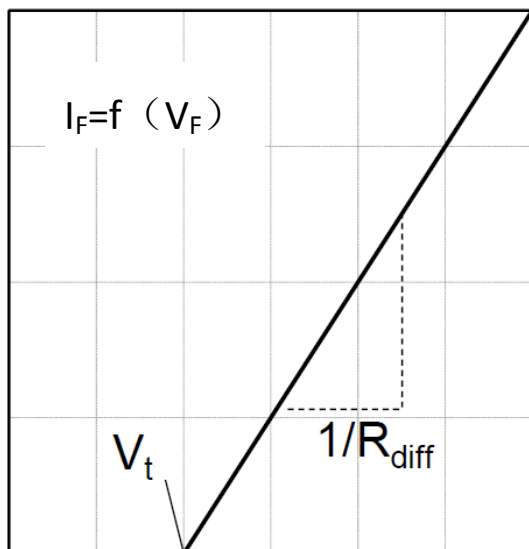
Package TO-247-3



| Symbol | Min. (mm) | Typ. (mm) | Max. (mm) |
|--------|-----------|-----------|-----------|
| A | 14.18 | 15.75 | 17.33 |
| B | 18.45 | 20.5 | 22.55 |
| C | 4.50 | 5.00 | 5.50 |
| D | 3.15 | 3.50 | 3.85 |
| E | 1.08 | 1.20 | 1.32 |
| F | 18.27 | 20.30 | 22.33 |
| G | 4.21 | 4.68 | 5.15 |
| H | 4.91 | 5.46 | 6.01 |

Simplified Diode Model (Per Leg)

Equivalent IV Curve for Model



Mathematical Equation

$$V_F = V_t + I_F \times R_{diff}$$

$$V_t = -0.0011 \times T_j + 1 \text{ [V]}$$

$$R_{diff} = 2.3 \times 10^{-6} \times T_j^2 + 4.7 \times 10^{-4} \times T_j + 0.086 \text{ [\Omega]}$$

Note:

T_j = Diode Junction Temperature In Degrees Celsius,
valid from 25°C to 175°C

I_F = Forward Current

Less than 12A